

CMOS LOGIC IC ELM7S14B Schmitt Inverter

■ General description

ELM7S14B is CMOS schmitt inverter IC. It realizes high speed operation similar to LS-TTL with lower power consumption by CMOS features. The inner circuit structure of 3-stage logic gate obtains wider noise immunity and constant output.

■ Features

- Same electrical characteristic as 74HC series (output current is around 1/2 of 74HC series)
- Low voltage operation : $I_{dd}=1.0\mu A$ (Max.)(Top=25°C)
- Wide power voltage range : 2.0V~6.0V
- High speed : $T_{pd}=5ns$ (Typ.)(Vdd=5.0V)
- Symmetrical output impedance : $|I_{oh}|=I_{ol}=2mA$ (Min.)(Vdd=4.5V)
- Small package : SOT-25

■ Application

- Cell phones
- Digital cameras
- Portable electrical appliances like PDA, etc.
- Computers and peripherals
- Digital electrical appliances like LCD TV sets, DVD recorders/players, STB, etc.
- Modification inside print board, adjustment of timing, solution to noise

■ Selection guide

ELM7S14B-EL

| Symbol | | |
|--------|------------------|------------------------|
| a | Function | 14 : Schmitt inverter |
| b | Product version | B |
| c | Taping direction | EL : Refer to PKG file |

ELM7S 1 4 B - EL
↑ ↑ ↑
a b c

■ Maximum absolute ratings

| Parameter | Symbol | Limit | Unit |
|--------------------------------|-----------|--------------|------|
| Power supply voltage | Vdd | -0.5~+7.0 | V |
| Input voltage | Vin | -0.5~Vdd+0.5 | V |
| Output voltage | Vout | -0.5~Vdd+0.5 | V |
| Input protection diode current | Iik | ± 20 | mA |
| Output parasitic diode current | Iok | ± 20 | mA |
| Output current | Iout | ± 25 | mA |
| VDD/GND current | Idd, Ignd | ± 25 | mA |
| Power dissipation | Pd | 200 | mW |
| Storage temperature | Tstg | -65~+150 | °C |



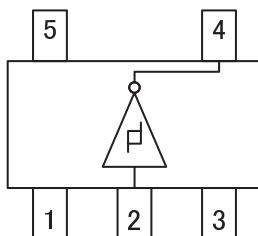
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■ Suggested operating condition

| Parameter | Symbol | Limit | | Unit |
|-----------------------|--------|----------|--------|------|
| Power voltage | Vdd | 2.0~6.0 | | V |
| Input voltage | Vin | 0~Vdd | | V |
| Output voltage | Vout | 0~Vdd | | V |
| Operating temperature | Top | -40~+85 | | °C |
| High-input down-time | tr, tf | Vdd=2.0V | 0~1000 | ns |
| | | Vdd=4.5V | 0~500 | |
| | | Vdd=6.0V | 0~400 | |

■ Pin configuration

SOT-25 (TOP VIEW)



| Pin No. | Pin name |
|---------|----------|
| 1 | NC |
| 2 | INY |
| 3 | GND |
| 4 | OUTX |
| 5 | VDD |

| Input | Output |
|-------|--------|
| INY | OUTX |
| Low | High |
| High | Low |

■ AC electrical characteristics

CL=15pF, tr=tf=6ns, Vdd=5V

| Parameter | Sym. | Vdd | Top=25°C | | | Unit | Condition |
|------------------------|------|-----|----------|------|------|------|-----------------------|
| | | | Min. | Typ. | Max. | | |
| Output transition time | tTLH | | 5 | 10 | | ns | Refer to test circuit |
| | tTHL | | 5 | 10 | | | |
| Propagation delay-time | tPLH | | 7 | 15 | | ns | Refer to test circuit |
| | tPHL | | 7 | 15 | | | |

CL=50pF, tr=tf=6ns

| Parameter | Sym. | Vdd | Top=25°C | | | Top=-40~+85°C | | Unit | Condition | |
|---------------------------|------|-----|----------|------|------|---------------|------|------|-----------------------|--|
| | | | Min. | Typ. | Max. | Min. | Max. | | | |
| Output transition time | tTLH | 2.0 | 50 | 125 | | 155 | | ns | Refer to test circuit | |
| | | 4.5 | 14 | 25 | | 31 | | | | |
| | | 6.0 | 12 | 21 | | 26 | | | | |
| | tTHL | 2.0 | 50 | 125 | | 155 | | ns | | |
| | | 4.5 | 14 | 25 | | 31 | | | | |
| | | 6.0 | 12 | 21 | | 26 | | | | |
| Propagation delay-time | tPLH | 2.0 | 48 | 100 | | 125 | | ns | Refer to test circuit | |
| | | 4.5 | 12 | 20 | | 25 | | | | |
| | | 6.0 | 9 | 17 | | 21 | | | | |
| | tPHL | 2.0 | 48 | 100 | | 125 | | ns | | |
| | | 4.5 | 12 | 20 | | 25 | | | | |
| | | 6.0 | 9 | 17 | | 21 | | | | |
| Input capacity | Cin | | 5 | 10 | | 10 | pF | | | |
| Equivalent inner capacity | Cpd | | 10 | | | | pF | | | |

* Cpd is IC's inner equivalent capacity which is calculated from non-loaded operating current consumption referred to test circuit.

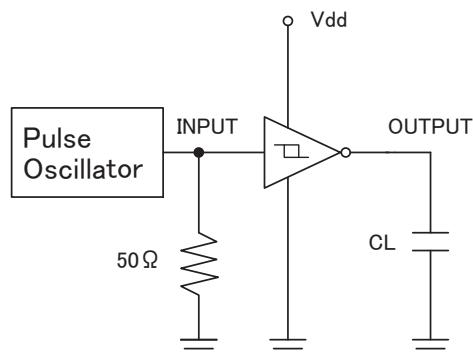
Averaged operating current consumption at non load is calculated as following formula: $Idd(\text{opr}) = Cpd \cdot Vdd \cdot f_{in} + Idd$

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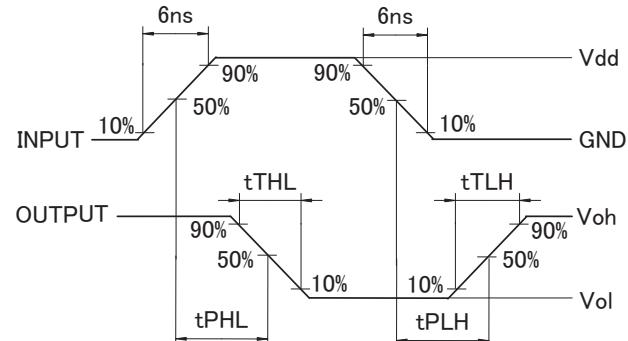
■ DC electrical characteristics

| Parameter | Sym. | Vdd | Top=25°C | | | Top=-40~+85°C | | Unit | Condition | |
|--------------------|------|-----|----------|------|------|---------------|------|------|---|--|
| | | | Min. | Typ. | Max. | Min. | Max. | | | |
| Threshold voltage | Vt+ | 2.0 | | | 1.50 | | 1.50 | V | | |
| | | 4.5 | | | 3.15 | | 3.15 | | | |
| | | 6.0 | | | 4.20 | | 4.20 | | | |
| | Vt- | 2.0 | 0.30 | | | 0.30 | | V | | |
| | | 4.5 | 0.90 | | | 0.90 | | | | |
| | | 6.0 | 1.20 | | | 1.20 | | | | |
| Hysteresis voltage | Vh | 2.0 | 0.20 | | 1.20 | 0.20 | 1.20 | V | | |
| | | 4.5 | 0.40 | | 2.25 | 0.40 | 2.25 | | | |
| | | 6.0 | 0.60 | | 3.00 | 0.60 | 3.00 | | | |
| Output voltage | Voh | 2.0 | 1.90 | 2.00 | | 1.90 | | V | Vin=Vih or Vil Ioh=-20μA Ioh=-2mA Ioh=-2.6mA | |
| | | 4.5 | 4.40 | 4.50 | | 4.40 | | | | |
| | | 6.0 | 5.90 | 6.00 | | 5.90 | | | | |
| | | 4.5 | 4.18 | 4.31 | | 4.13 | | | | |
| | | 6.0 | 5.68 | 5.80 | | 5.63 | | | | |
| | Vol | 2.0 | | 0.00 | 0.10 | | 0.10 | V | Vin=Vih Iol=20μA Iol=2mA Iol=2.6mA | |
| | | 4.5 | | 0.00 | 0.10 | | 0.10 | | | |
| | | 6.0 | | 0.00 | 0.10 | | 0.10 | | | |
| | | 4.5 | | 0.17 | 0.26 | | 0.33 | | | |
| | | 6.0 | | 0.18 | 0.26 | | 0.33 | | | |
| Input current | Iin | 6.0 | -0.1 | | 0.1 | -1.0 | 1.0 | μ A | Vin=Vdd or GND | |
| Static current | Idd | 6.0 | | | 1.0 | | 10.0 | μ A | Vin=Vdd or GND | |

■ Test circuit



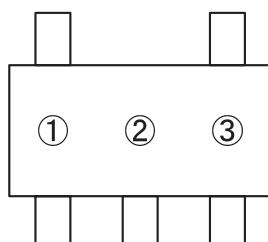
■ Measured wave pattern



* Output should be opened when measuring current consumption.

■ Marking

SOT-25



| No. | Mark | Content |
|-----|-------------------------|--------------|
| ① | E | ELM7S series |
| ② | A | ELM7S14B |
| ③ | A~Z (except I, O, X) | Lot No. |